



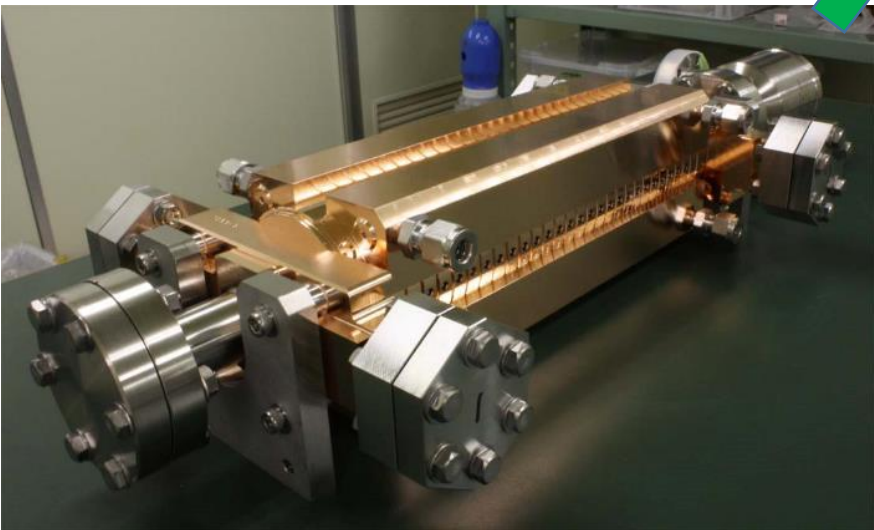
Ultimate Field Gradient in Metal Structures



Ultimate Field Gradient **Limitation** in Metal Structures

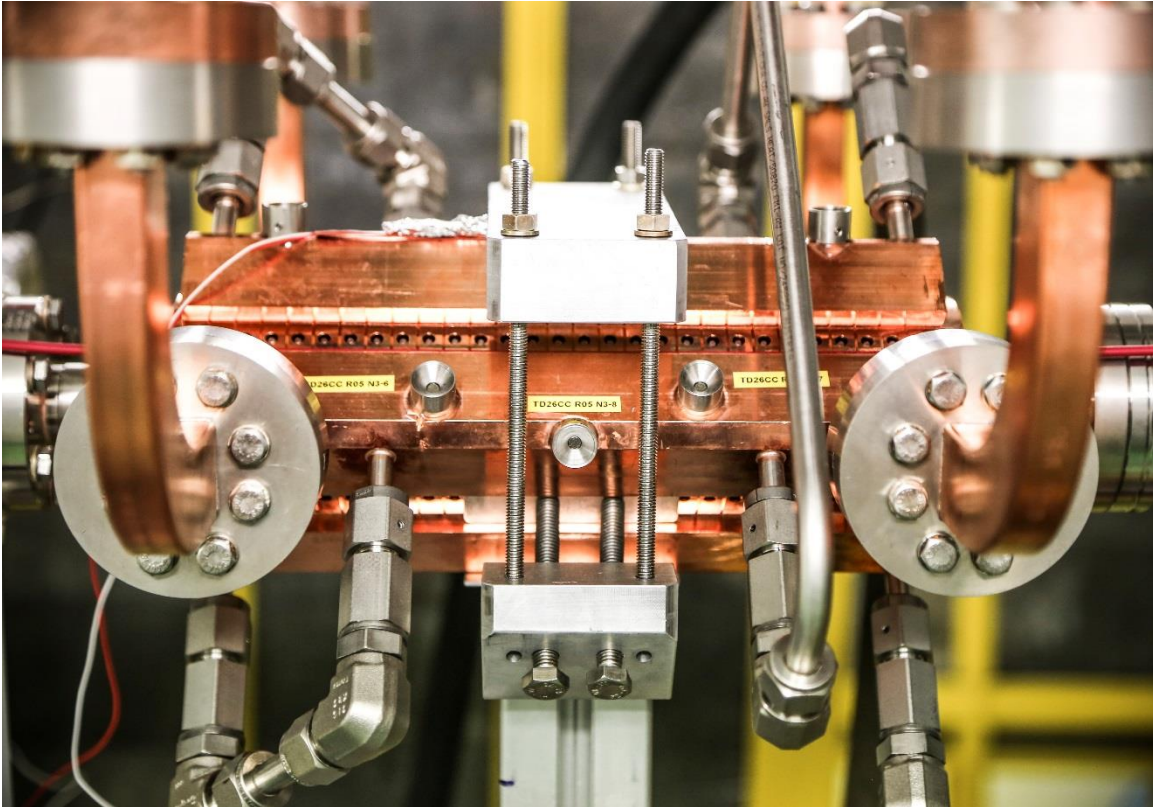


Background

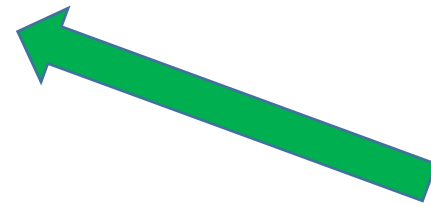


In order to reach multi-TeV e^+e^- collision energies the CLIC collaboration has invested significant effort to develop 100 MV/m gradient accelerating structures.

- 11.994 GHz, X-band
- OFE copper, hydrogen bonded 1040 °C
- 100 MV/m accelerating gradient
- Input power ≈ 50 MW
- Pulse length ≈ 200 ns
- Repetition rate 50-400 Hz



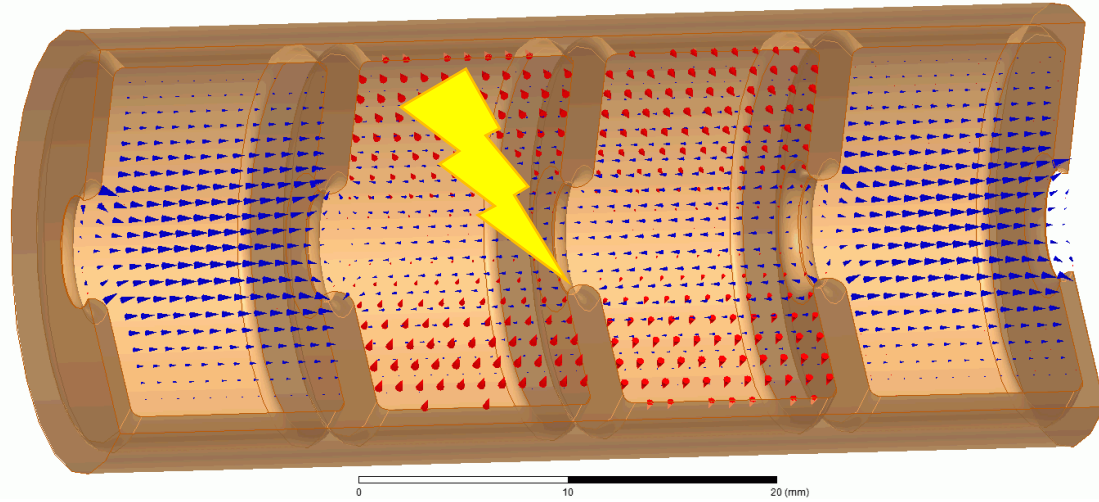
25 cm



Micron-precision disk



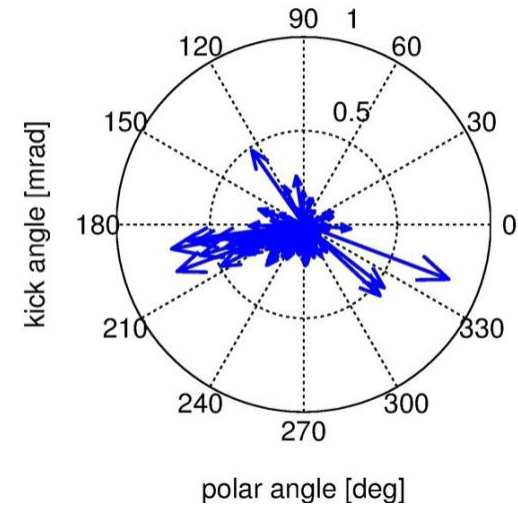
Vacuum arcing



One of the main limitations we have is **vacuum arcing, aka breakdown**,

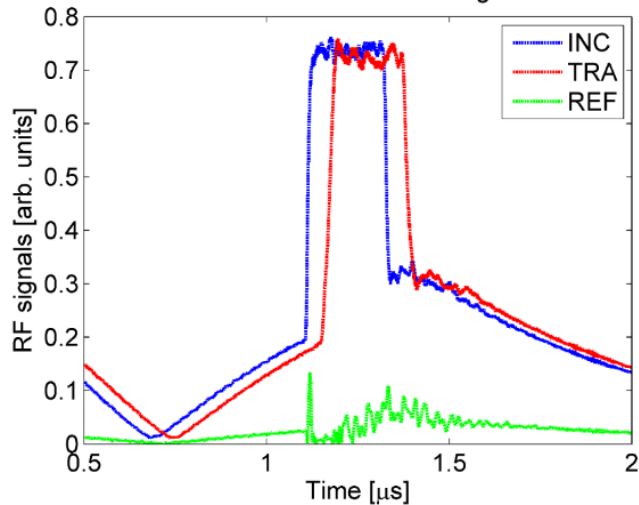
- Suppresses power flow reducing acceleration
- Gives beam transverse kick

Kicks to the beam measured on screen CA.MTV0790

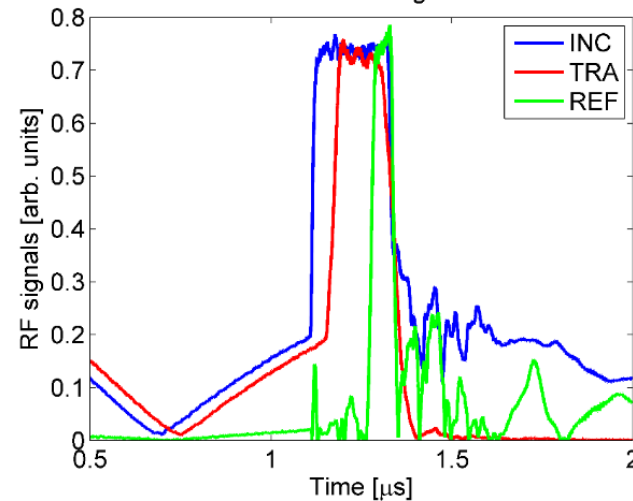


Transverse effect on beam measured in CTF3, A. Palaia

Previous to Breakdown signal



Breakdown signal



Effect on rf



Very high-field vacuum arcs

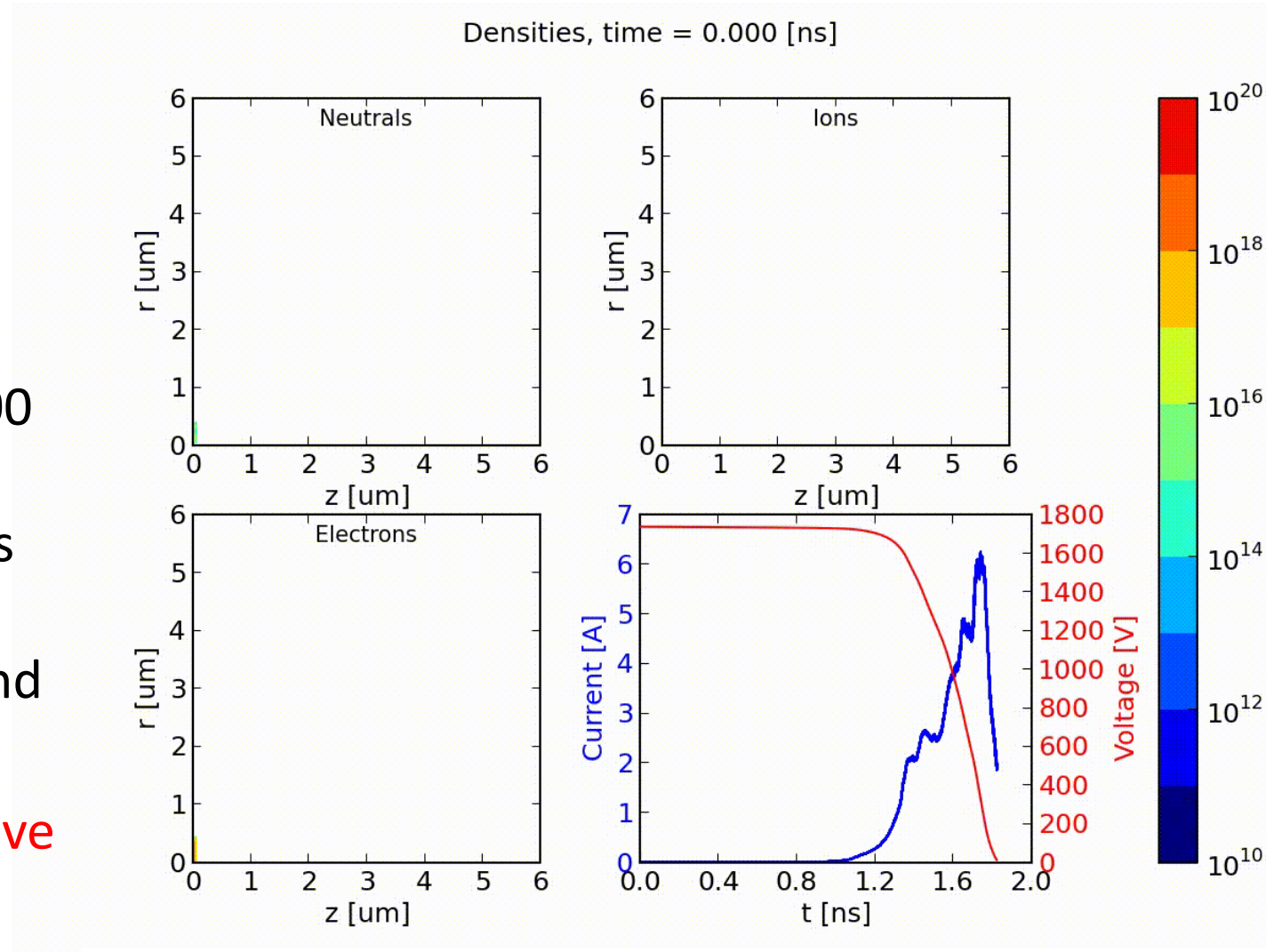


Vacuum arcs – the formation of plasma accompanied by large electron currents - occur in many devices and applications.

What's so special about us?

- Very high surface electric fields, over 200 MV/m
- Opportunity to test over 20 rf structures and over 40 pulsed dc electrodes combined with significant theoretical and simulation effort.

We believe that we see processes which give fundamental field limits for copper.



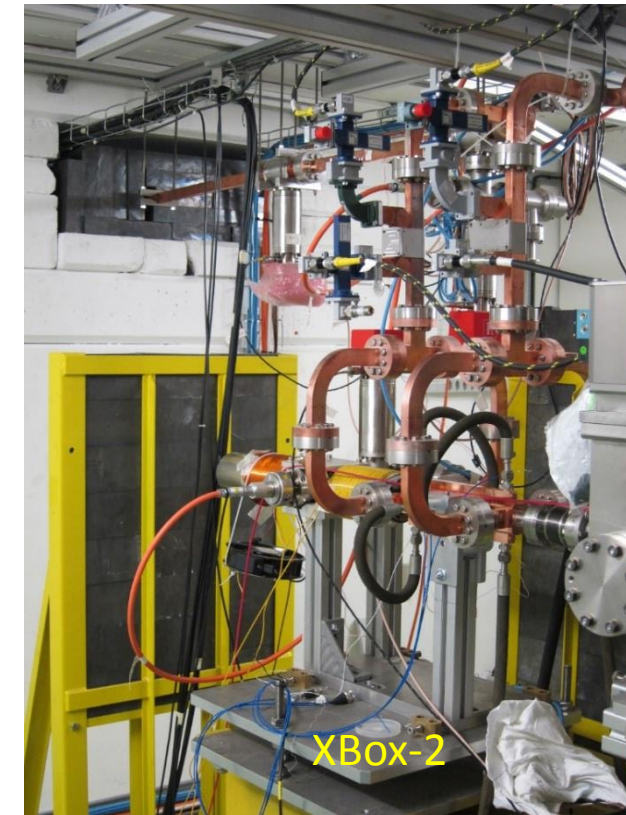
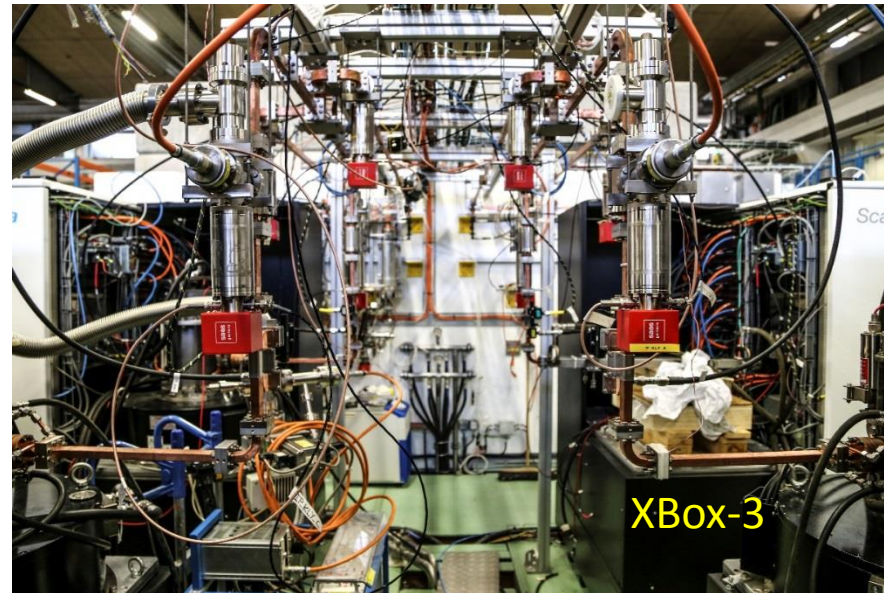
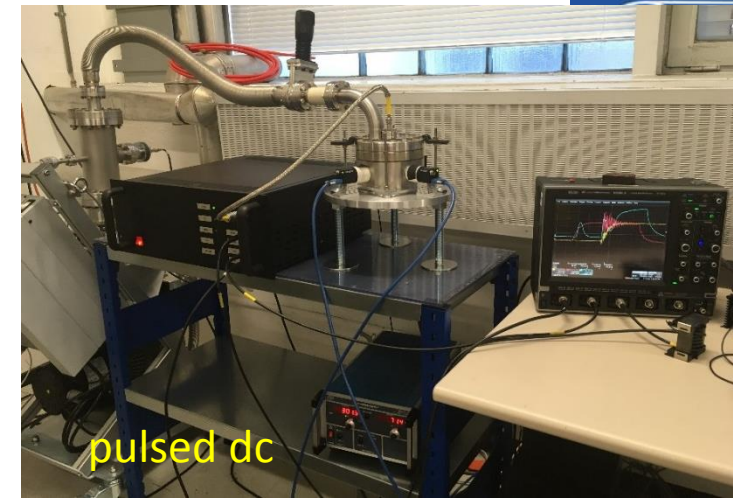
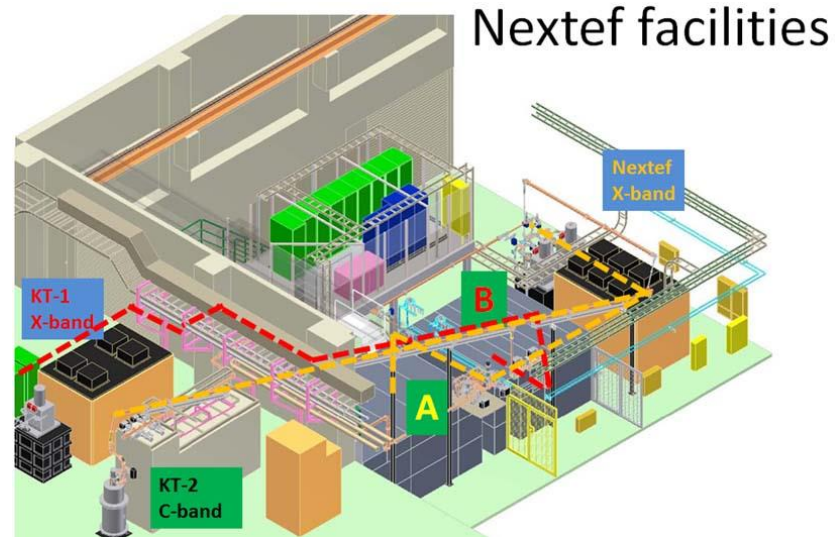
Onset of a vacuum arc simulated by ArcPIC, K. Sjobaek

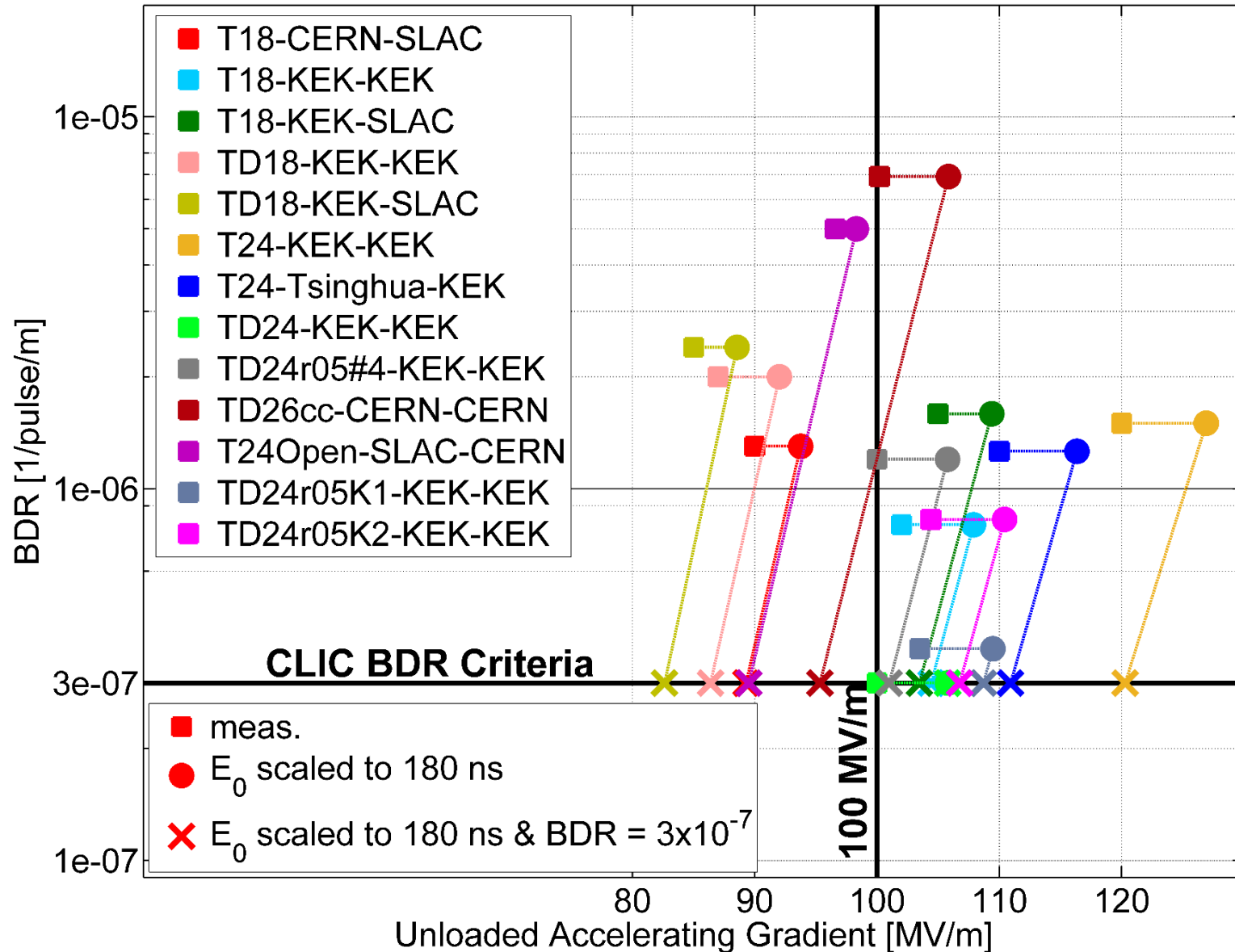


Where we do our experiments

Klystron-based test stands at CERN:

- XBox1 to 3
- NEXTEF at KEK
- Two pulsed-dc systems.





Currently under test:

XBox1 – TD26CC N2

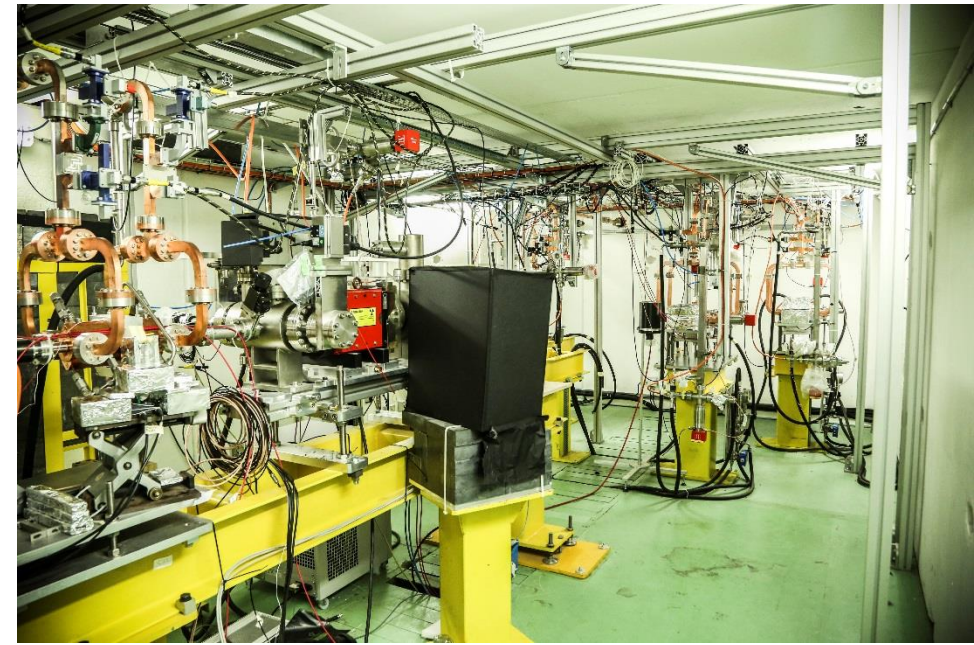
XBox2 – TD26CC N3

XBox3 – TD24CC SiC

T24 PSI

SBox - 3 GHz BTW

NEXTEF (KEK) – TD24 R05





Very high-field vacuum arcs, in more detail



Consider the vacuum arc **trigger**.

Need a **site** which produces enhanced **electron field emission** and **neutral atom emission**.

What is the nature of such a site?

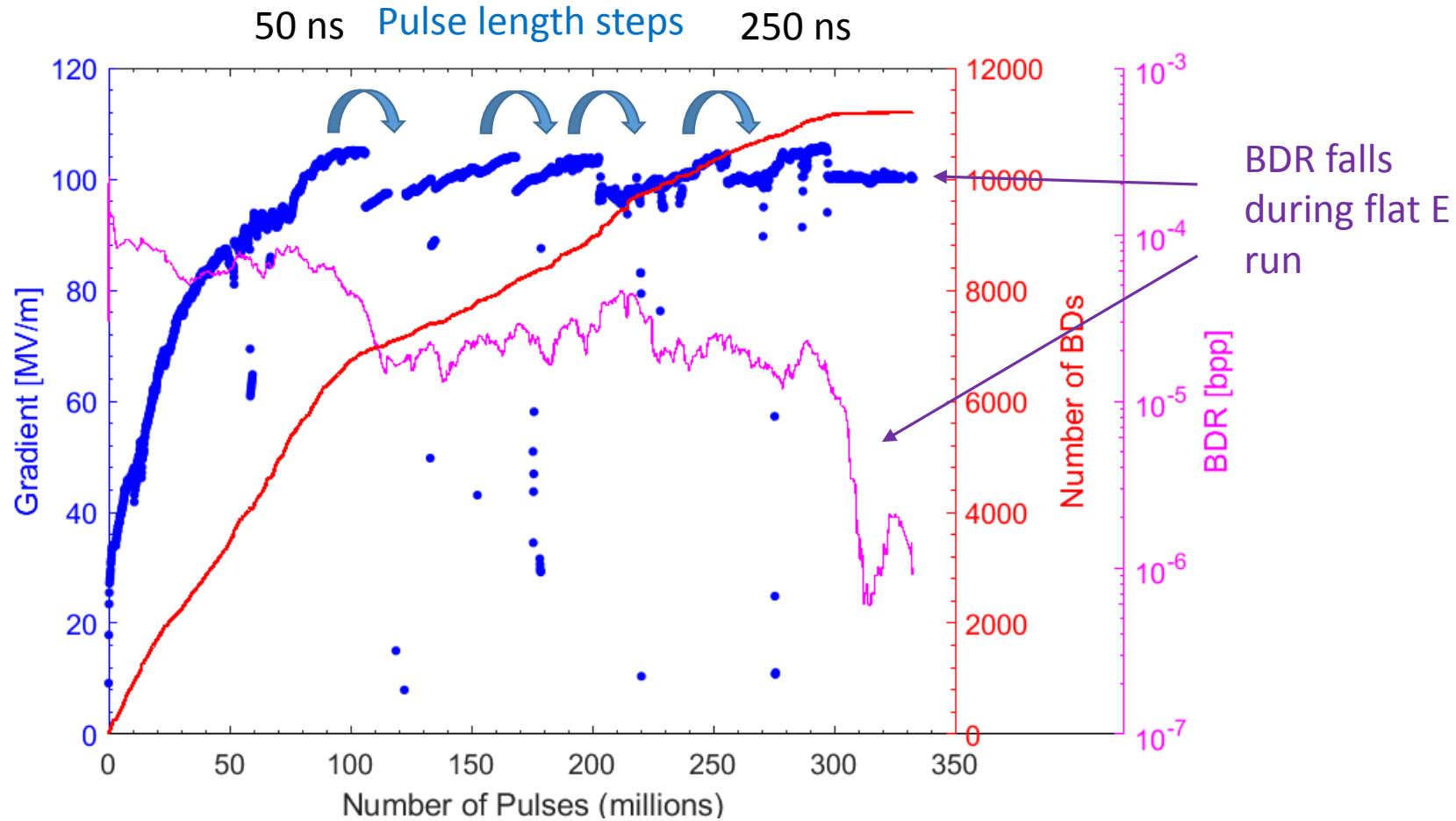
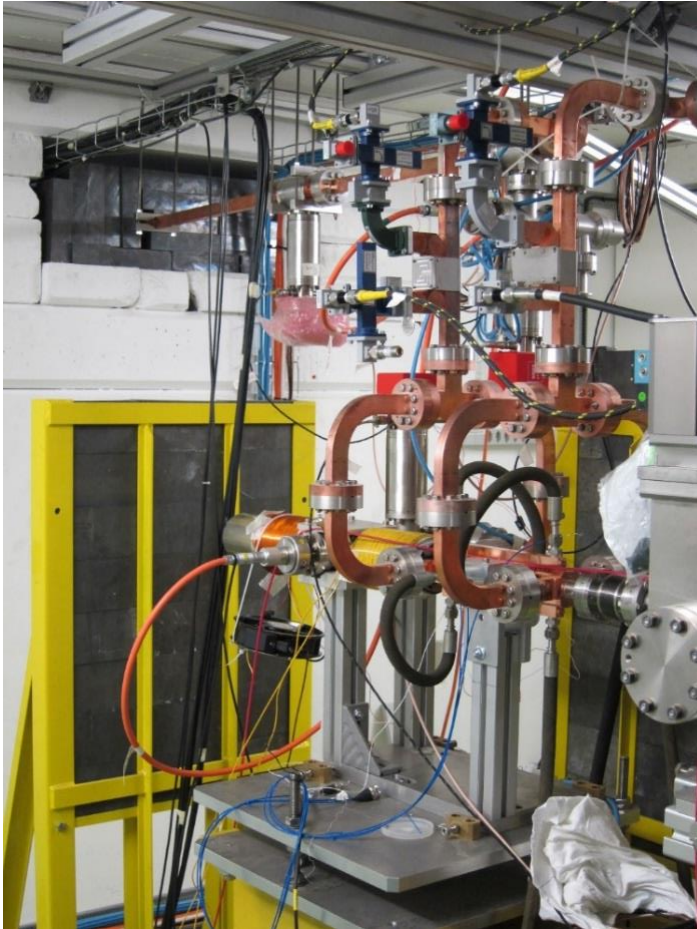
For most applications these are contaminants: dust, particles, oxides etc.

But at high fields, > 100 MV/m surface electric field, we see clear evidence of field-generated features – that give the ultimate field limit.

These features seem to form **below the surface** and are generated by **dislocation dynamics**.

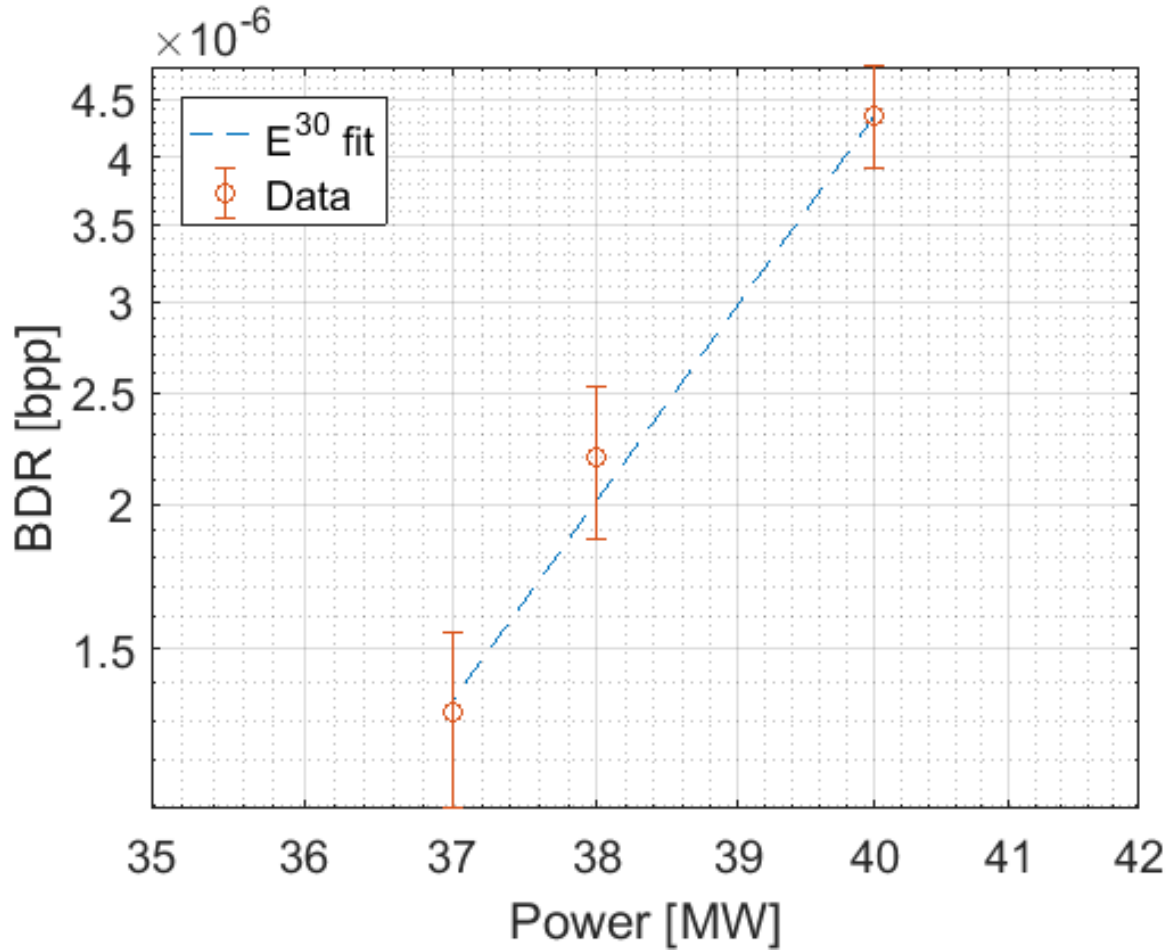
Conditioning

Accelerating structures do not run right away at full specification – pulse length and gradient need to be gradually increased while pulsing. Typical behaviour looks like this:



4 million pulses per day at 50 Hz

Walter Wuensch, CERN



Data taken in XBox-2 with TD26CC structure, T. Lucas

Regularly observed dependence:

$$BDR \propto E^{30} \tau^5$$

Physical model based on defect formation



$$BDR \propto e^{\frac{-E^f + \epsilon_0 E^2 \Delta V}{k_b T}}$$

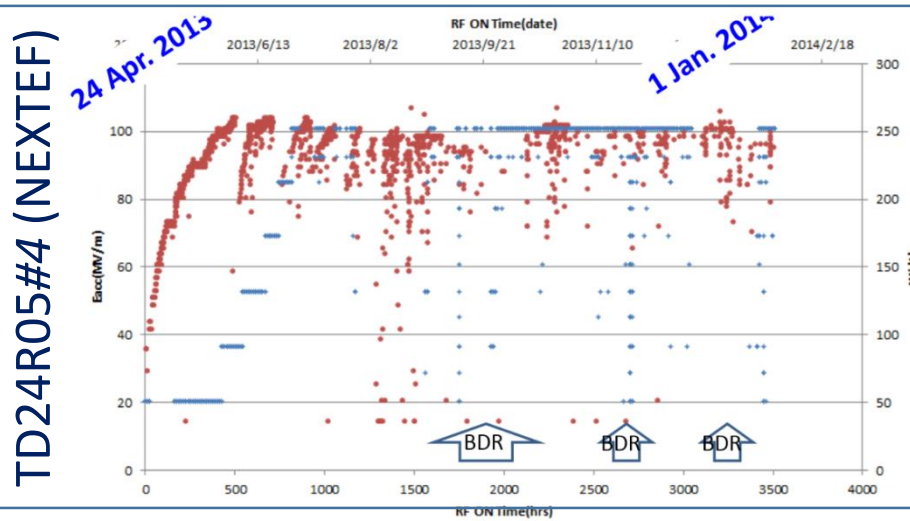
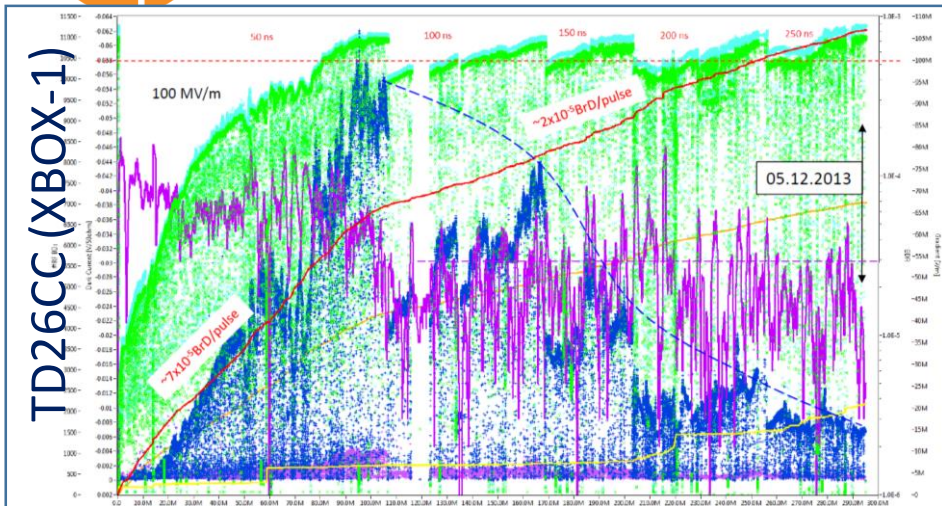
$$E^f = 0.8 \text{ eV}$$

$$\Delta V = 0.8 \times 10^{-24} \text{ m}^3$$

K. Nordlund, F. Djurabekova, *Defect model for the dependence of breakdown rate on external electric fields*, Phys. Rev. ST Accel. Beams 15, 071002 (2012)



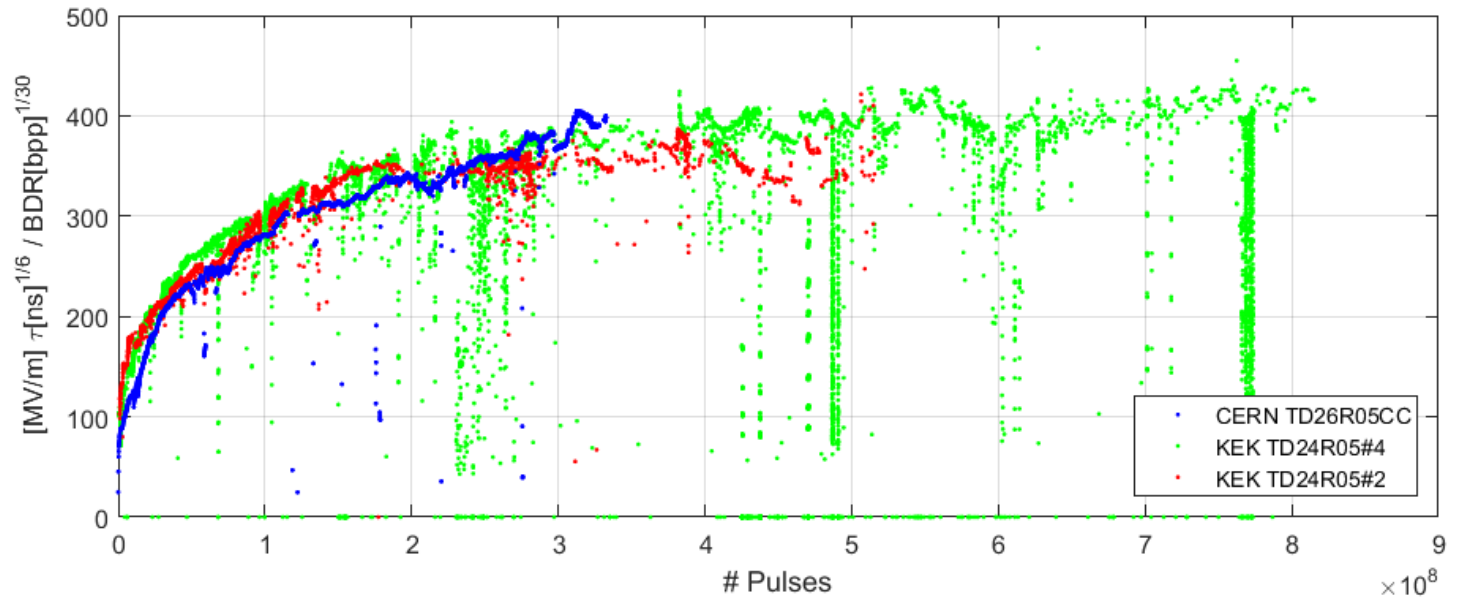
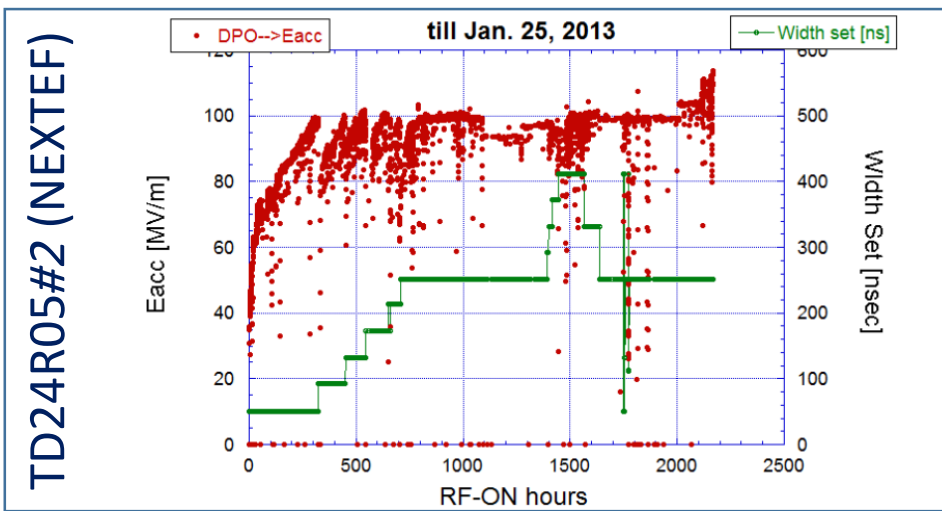
Comparison of three similar structures



We normalize by:

$$BDR \propto E^{30} \tau^5$$

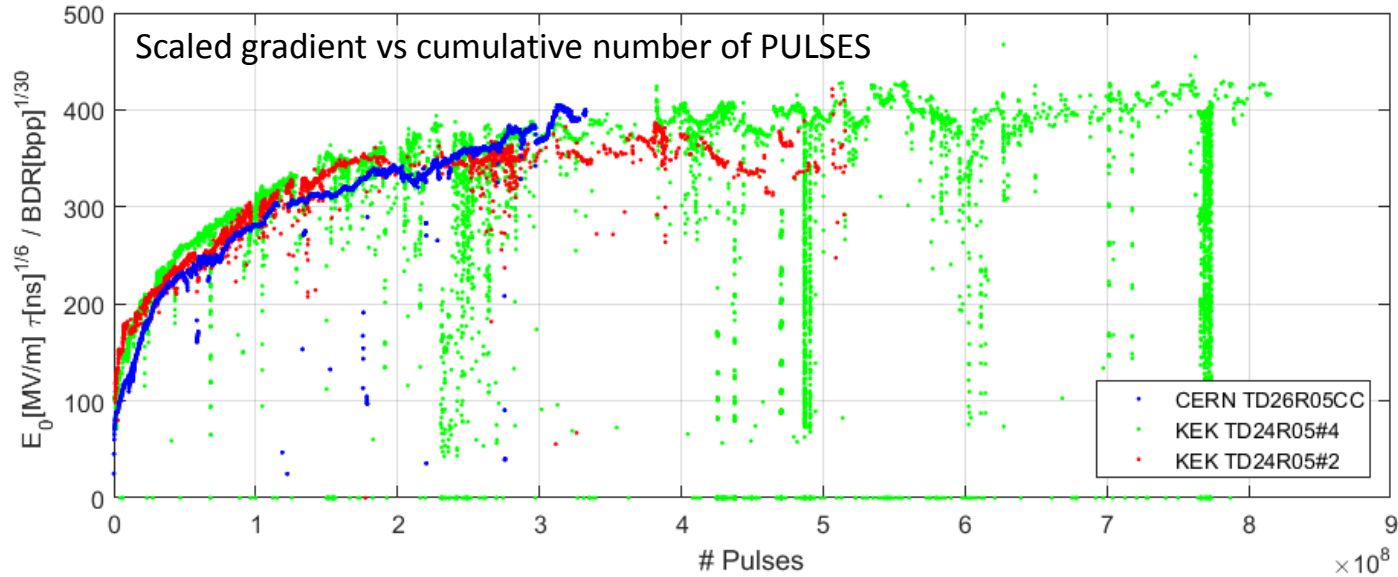
And get



Interpretation: Conditioning is a reproducible process which implies a well defined physical mechanism.

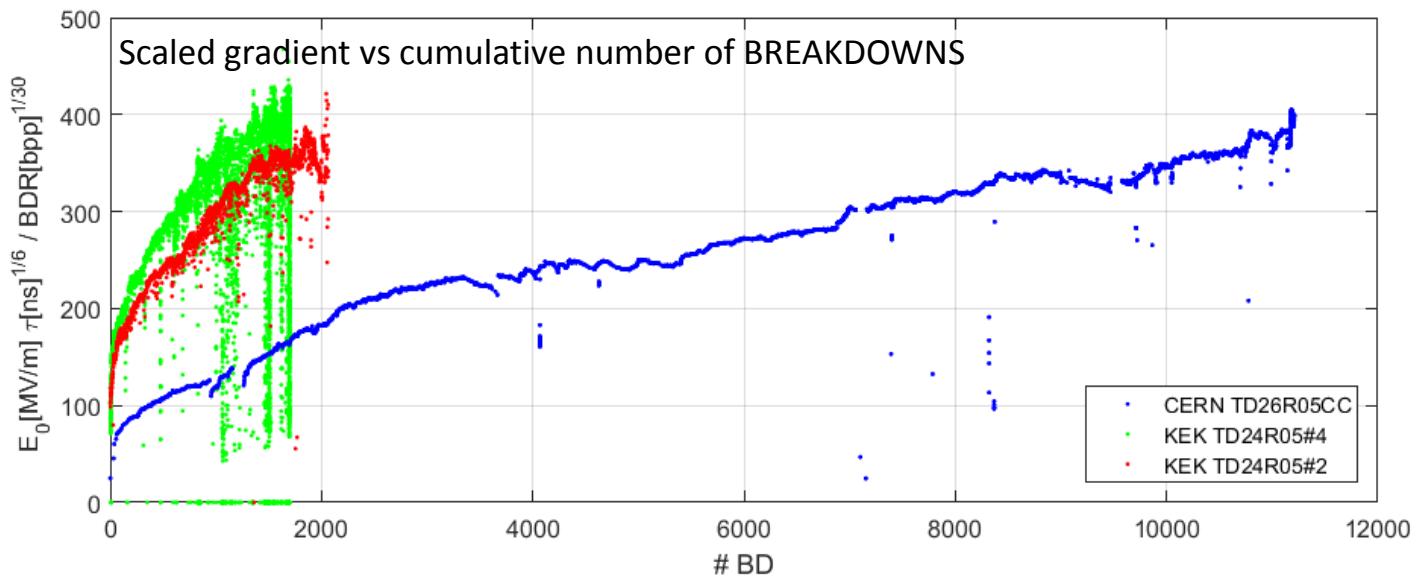


Comparing conditioning

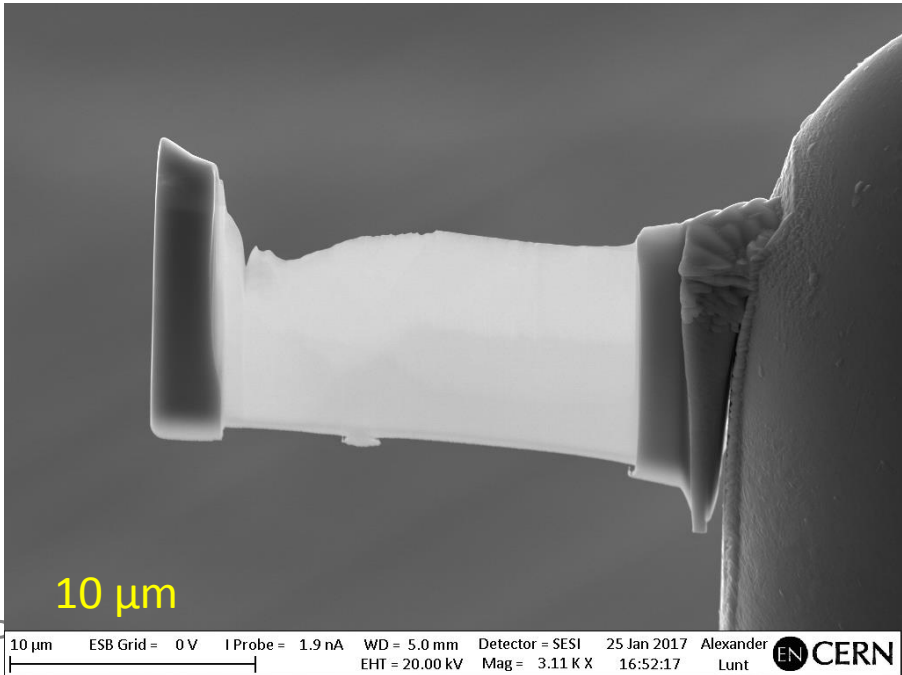
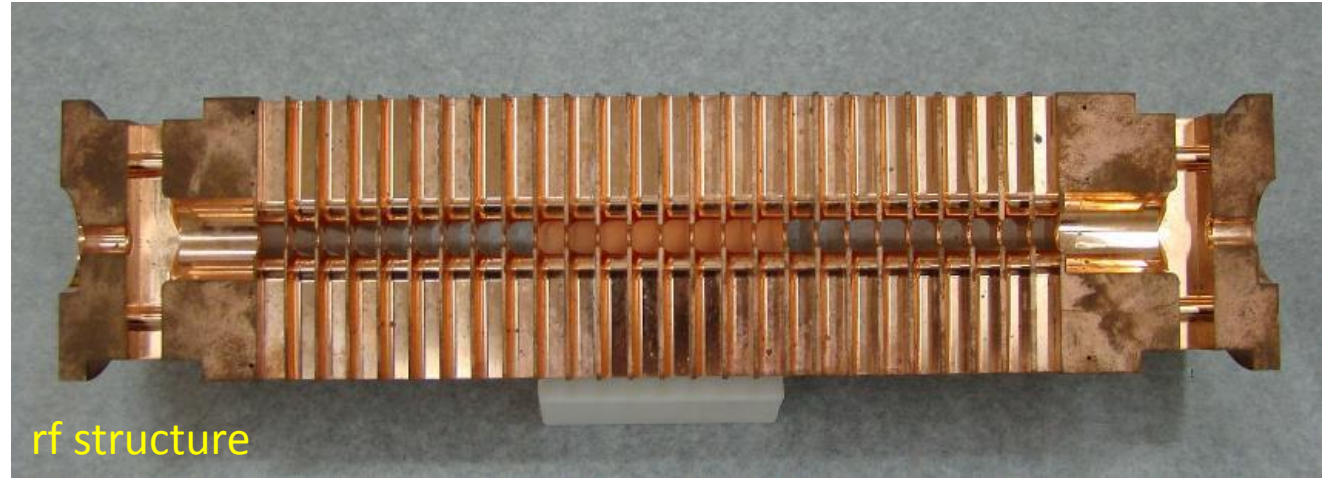
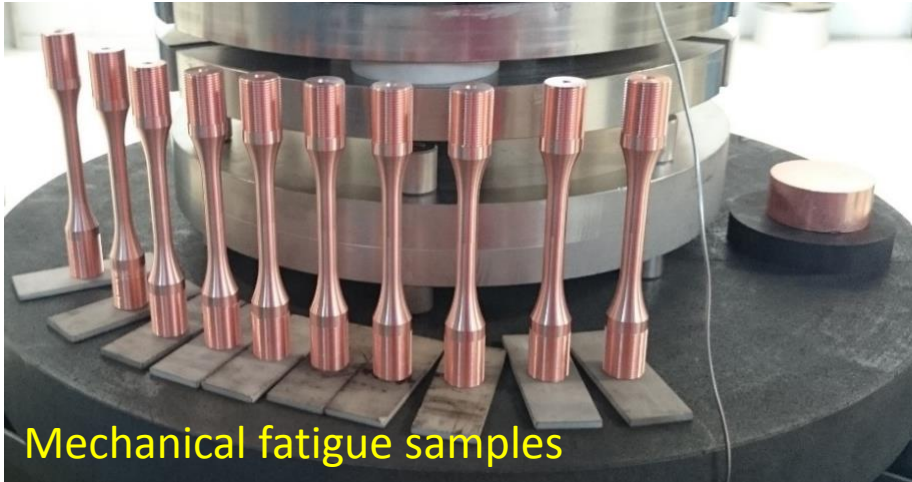


vs. number of pulses

Interpretation – conditioning proceeds as the number of pulses *not* the number of breakdowns. This implies a steady modification of the structure for each pulse.



vs. number of Breakdowns

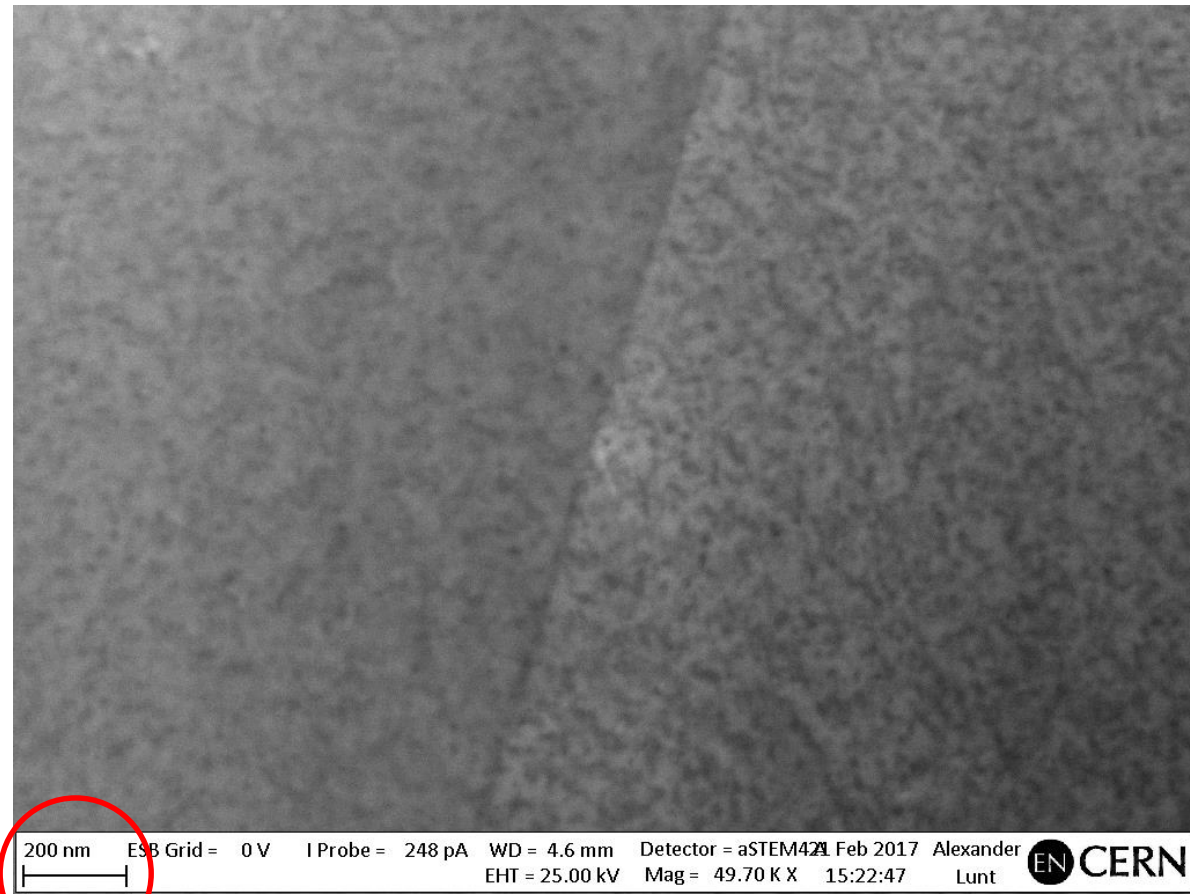


Experiment:

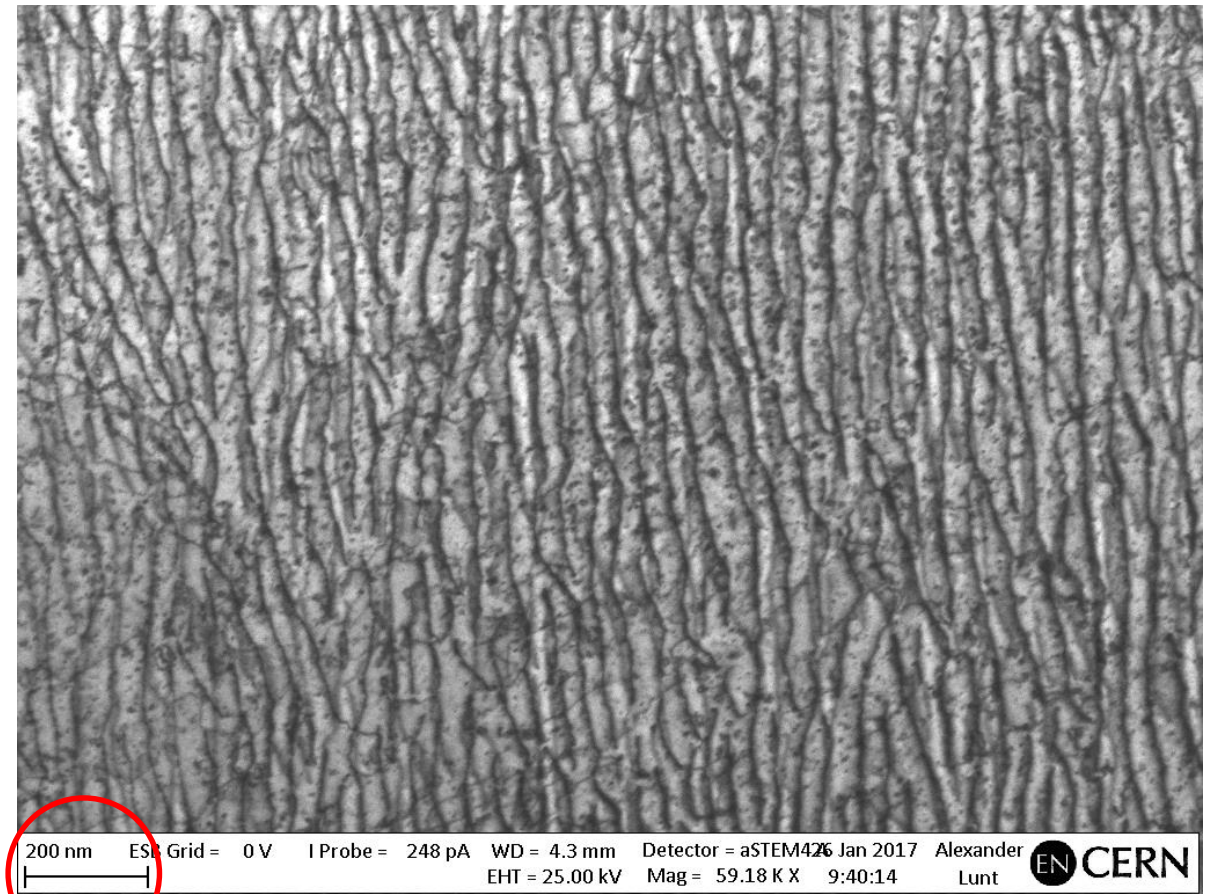
1. Build **rf structure**, standard procedure with 1040 °C bonding, and **mechanical sample** with same heat treatment.
2. Condition rf structure and fatigue mechanical sample.
3. Compare material state before/after/between using advanced microscopy techniques: FIB cutting lamella and image using STEM and TEM.



Mechanical fatigue – STEM images



After heat treatment



200 nm

After mechanical fatigue

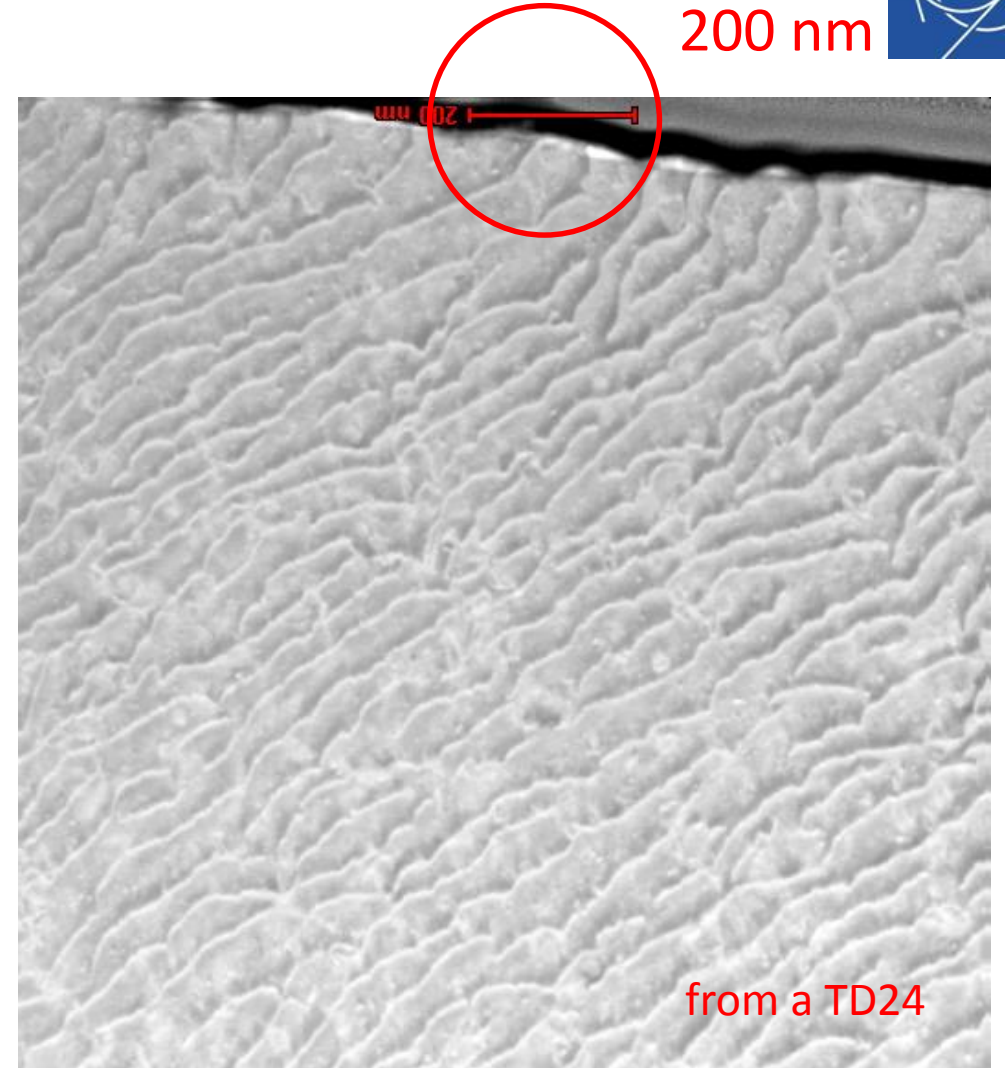
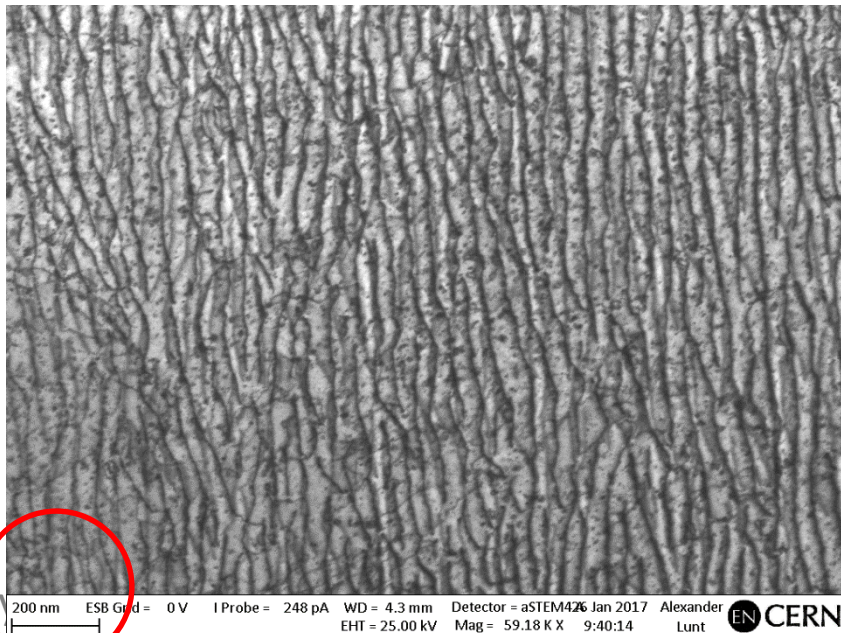
Formation of dislocation patterns characteristic of hardening.



Comparison of mechanical and rf samples



200 nm



After rf conditioning, high E field region – TEM image

A. Yashar, I. Popov



Interpretation



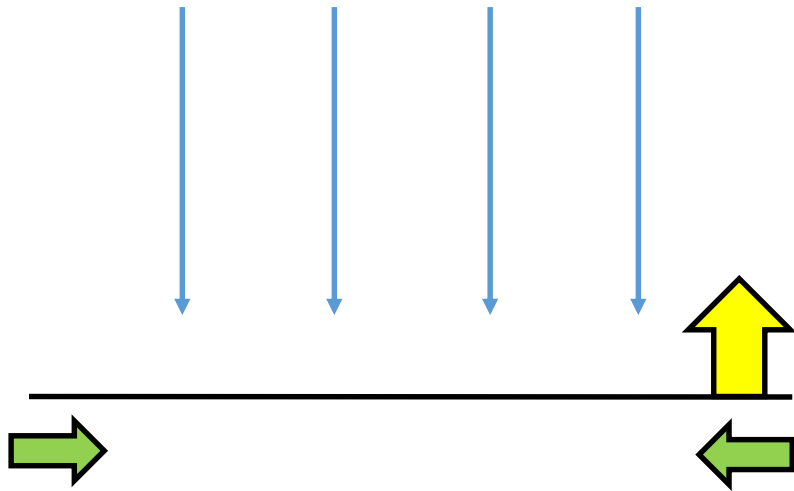
RF operation at high fields **produces dislocation patterns similar to fatigue** implying:

- A hardening process occurs during conditioning,
- Dislocation dynamics, formation and movement, are central to high-gradient behaviour.

Some numbers:

- Electric field stress is $\sigma = \frac{1}{2} \epsilon_0 E^2$ so for 250 MV/m surface field, 270 kPa – for perfect flat surface.
- The onset of plastic behaviour in Cu is of the order of kPa, so well above already at 100 MV/m surface field.
- Speed of sound in copper is .38 mm/100 ns, so bulk phenomenon.

Applied external electric field

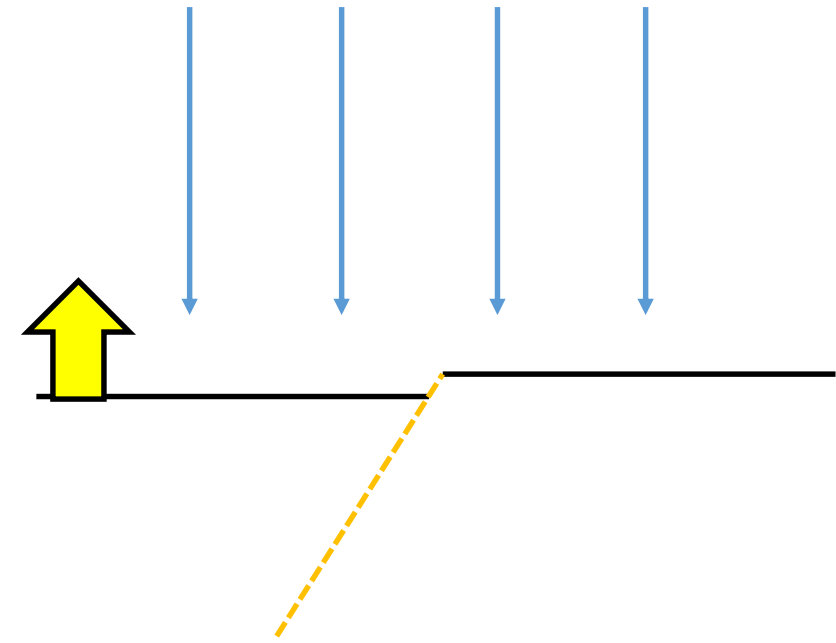


(Pulsed surface heating – not subject for today)

Vacuum

Tensile force

Copper

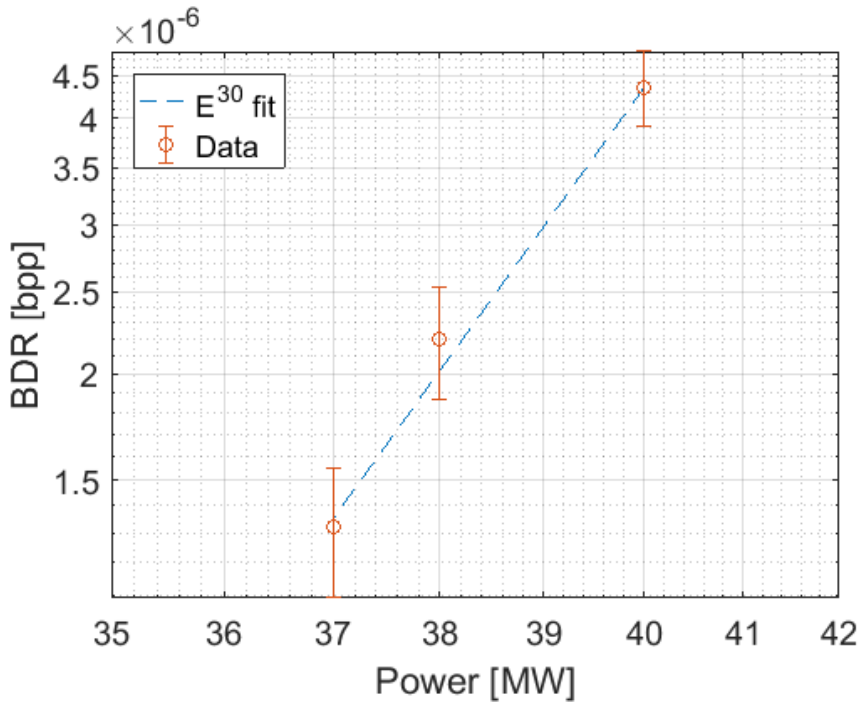
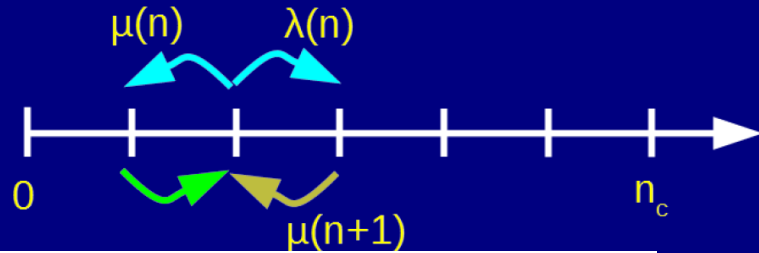


- Tensile stress induces plastic behaviour, i.e. creates dislocations.
- Dislocations move to surface to reduce energy.
- Projection of dislocation on surface in **nucleation point** for continuation of breakdown process (too little time today for rest of story)

Exact Solution: Master Equation

- Rates
- Conversion to Steps
- Solution Methods
- Exact Solution
- Metastable Approximation
- Simulation
- Choice of Parameters
- Experiment
- Conclusions

$$\frac{dP(n, t)}{dt} = \lambda(n-1)P(n-1, t) + \mu(n+1)P(n+1, t) - [\lambda(n) + \mu(n)]P(n, t)$$

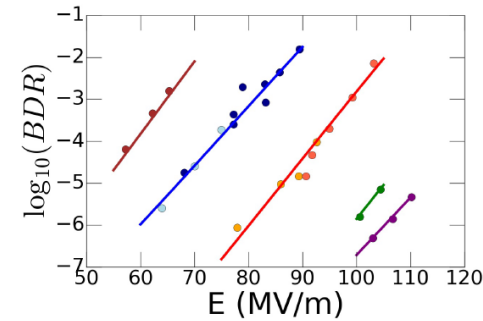


berg@mail.huji.ac.il

E. Engelberg

BDR dependence - II

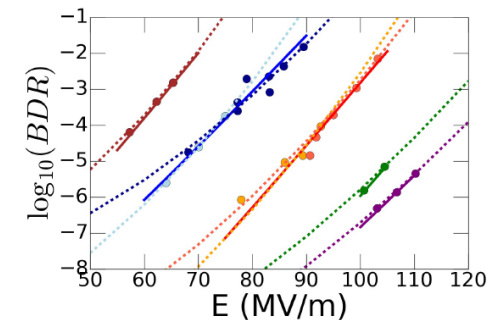
Experiment: Dependence on Field



A. Grudiev, S. Calatroni, and W. Wuensch, PRST-AB 12, 102001 (2009)
 K. Nordlund and F. Djurabekova, PRST-AB 15, 071002 (2012)

Good fits, consistent with the previously proposed power law!

$$\tau \sim E^\nu, \quad 25 < \nu < 30$$





An explanation of high-field conditioning



Copper in its annealed state always has some, but very mobile, dislocations.

Stresses from rf pulses create and move dislocations, which migrate towards surface creating surface features which nucleate breakdown sites.

This dynamic gives us breakdown rate.

Movement of dislocations also form interlocking “sessile” patterns, which reduce movement of later-formed dislocations.

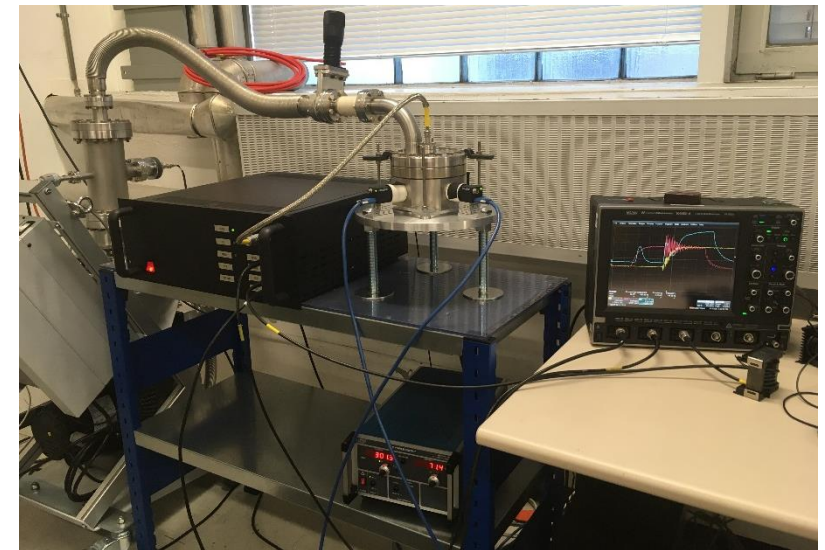
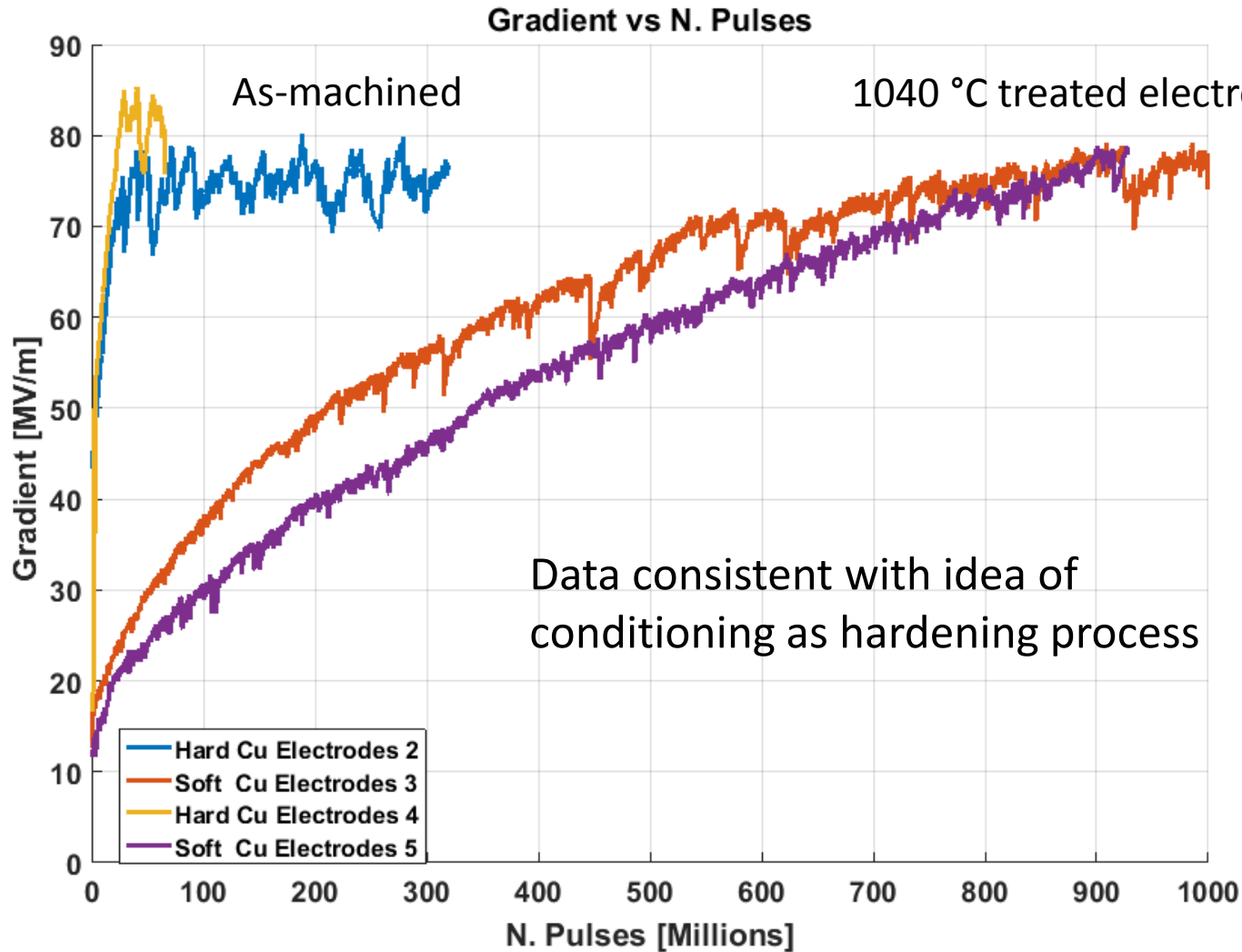
This interplay is what lies behind field dependence, conditioning and gives ultimate gradient.

BD nucleation as a critical transition in dislocation population, Y. Ashkenazy

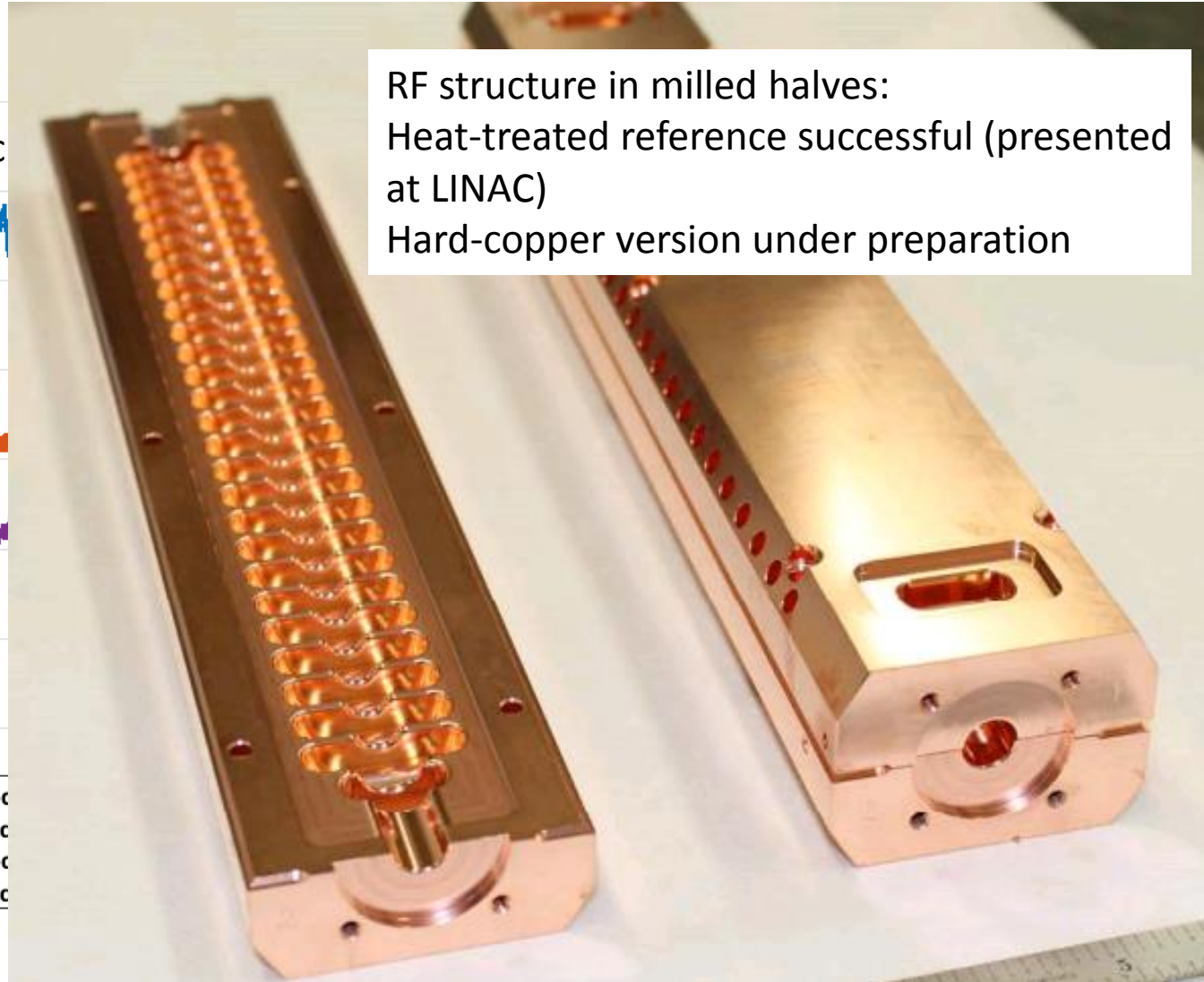
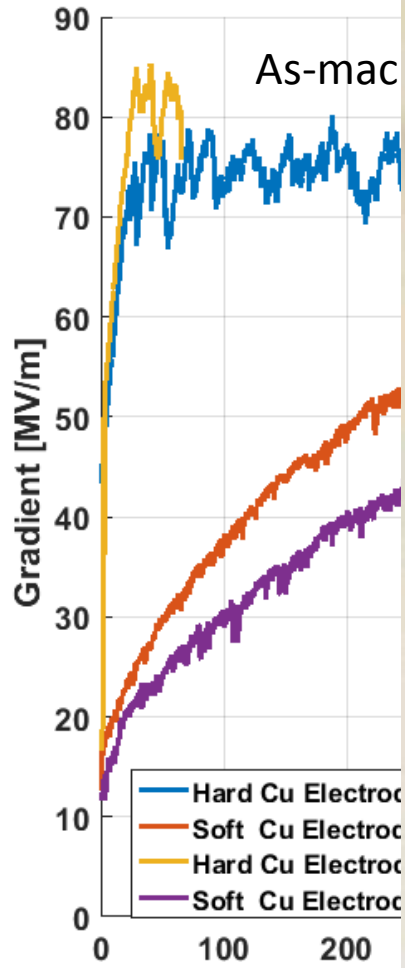
Stochastic Model of Breakdown Nucleation under Intense Electric Fields, E. Engelberg

both at MeVArc2017 <https://indico.cern.ch/event/521667/>

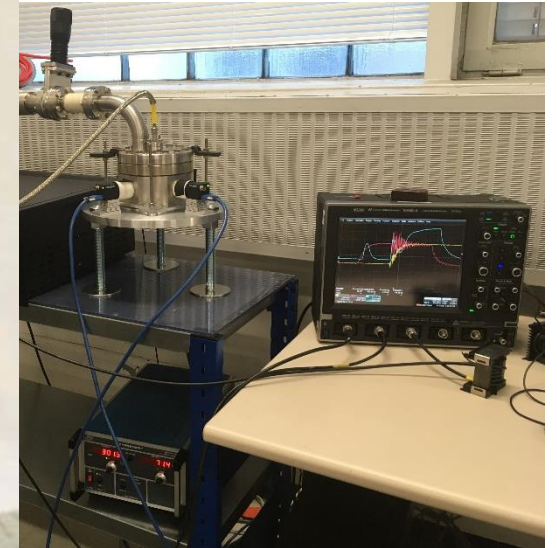
Hard vs. soft copper in pulsed dc system



Hard vs. soft copper in pulsed dc system



RF structure in milled halves:
 Heat-treated reference successful (presented at LINAC)
 Hard-copper version under preparation





Summary

- Breakdown rate vs gradient,
- Conditioning vs number of pulses,
- Material state before and after conditioning,

All point to the importance of dislocation dynamics in determining behaviour and Ultimate Gradient in high-gradient normal conducting rf structures.

A crucial stage of the action is below the surface!

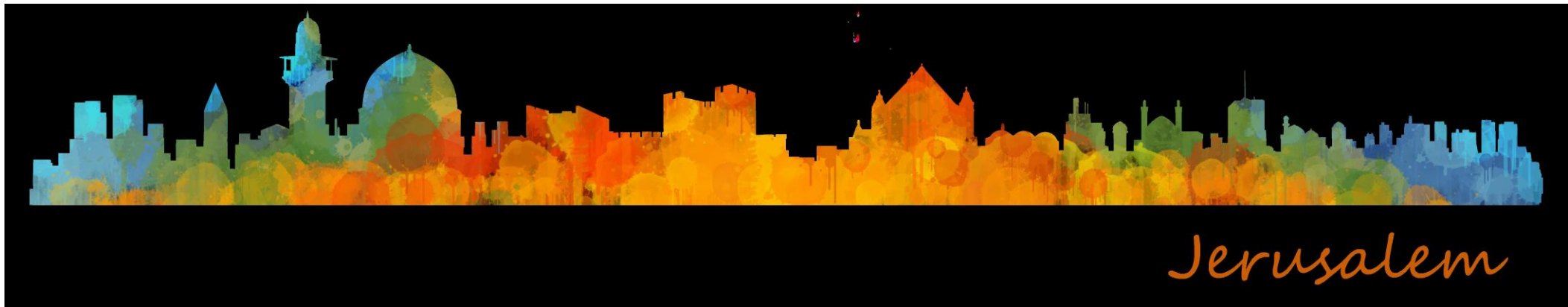


Acknowledgements



The results presented are the fruit of an extensive effort of many colleagues over many years. I would like to sincerely acknowledge, and thank:

- Flyura Djurabekova and her team at the University of Helsinki
- Yinon Ashkenazy and his team at the University of Jerusalem
- Vahur Zhadin and his team at the University of Tartu
- My high-gradient CLIC colleagues at CERN

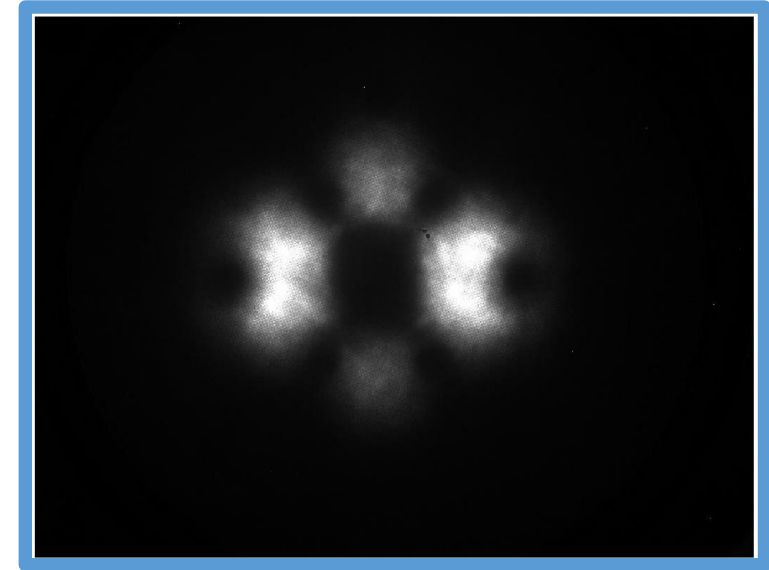
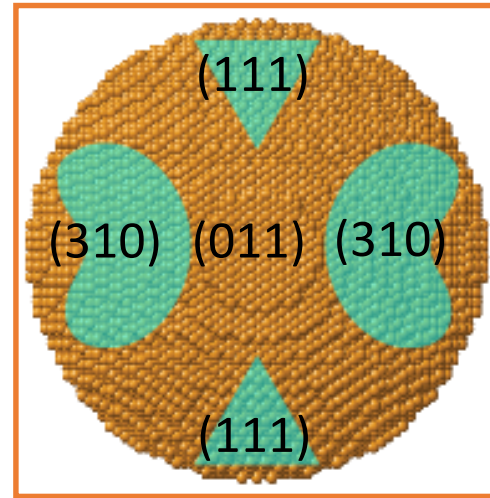
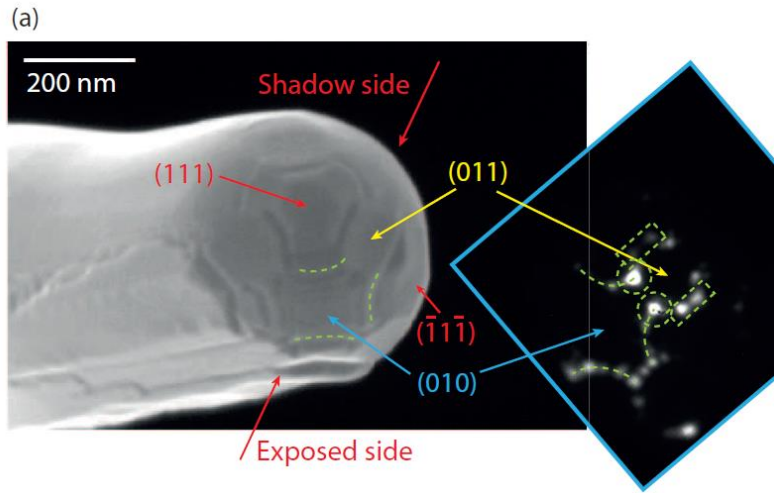


Much more at Mechanisms of Vacuum Arcs, MeVArc2017

<https://indico.cern.ch/event/521667/overview>



Extra slides
(next step in breakdown)

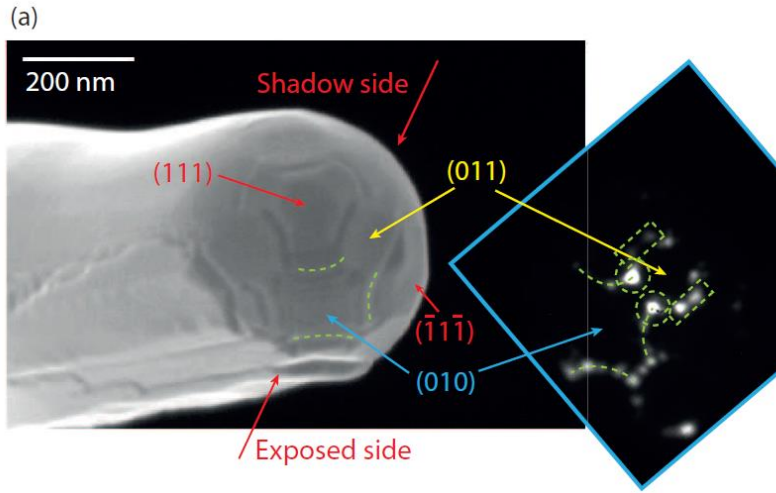


Tungsten tip used in ultra-fast electron diffraction.

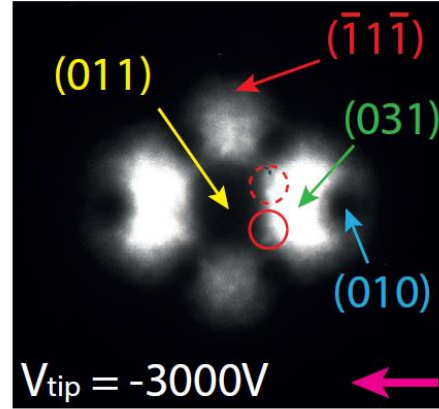
Tips deteriorate under laser pulsing but:

- Small area to uniquely identify characteristics of field emission sites
- Intense femtosecond fields opportunity to benchmark molecular dynamics and kinetic Monte Carlo codes

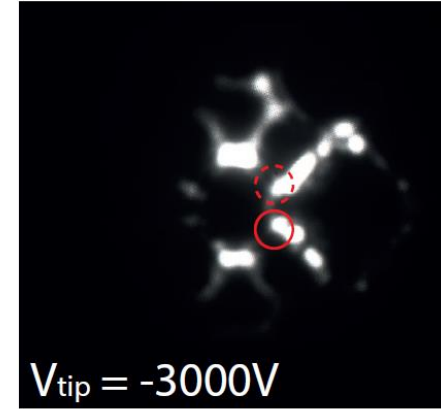
Hirofumi Yanagisawa, et. al. *Laser-induced asymmetric faceting and growth of a nano-protrusion on a tungsten tip*, APL Photonics 1, 091305 (2016); doi: 10.1063/1.4967494



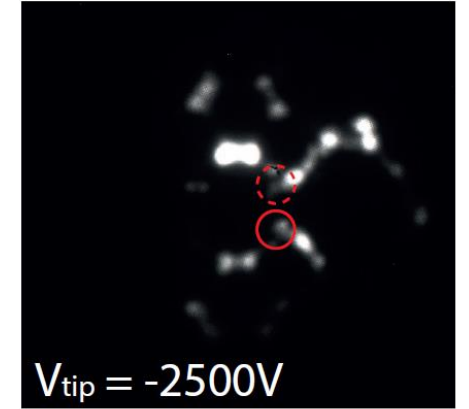
(a) 0 min



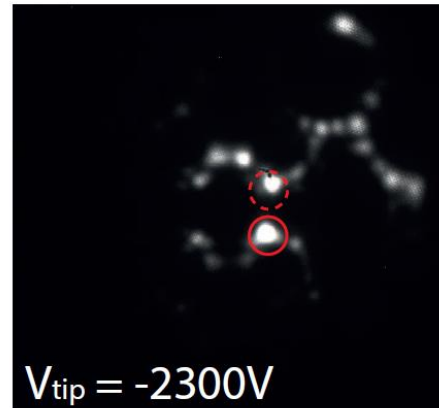
(b) 5 min



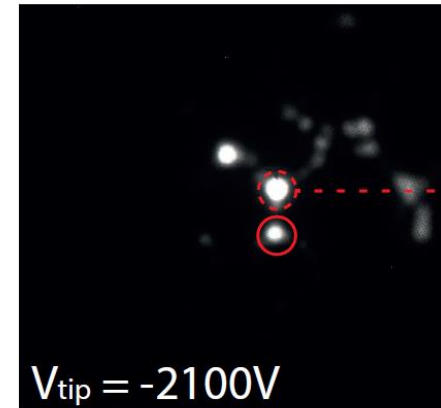
(c) 40 min



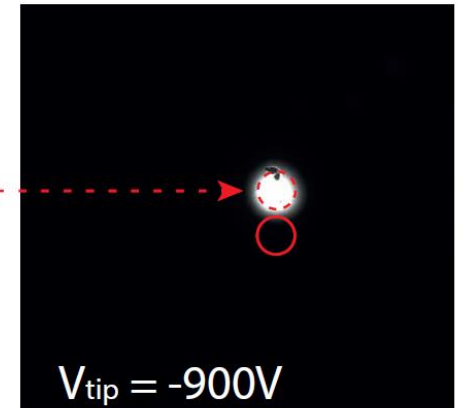
(d) 140 min



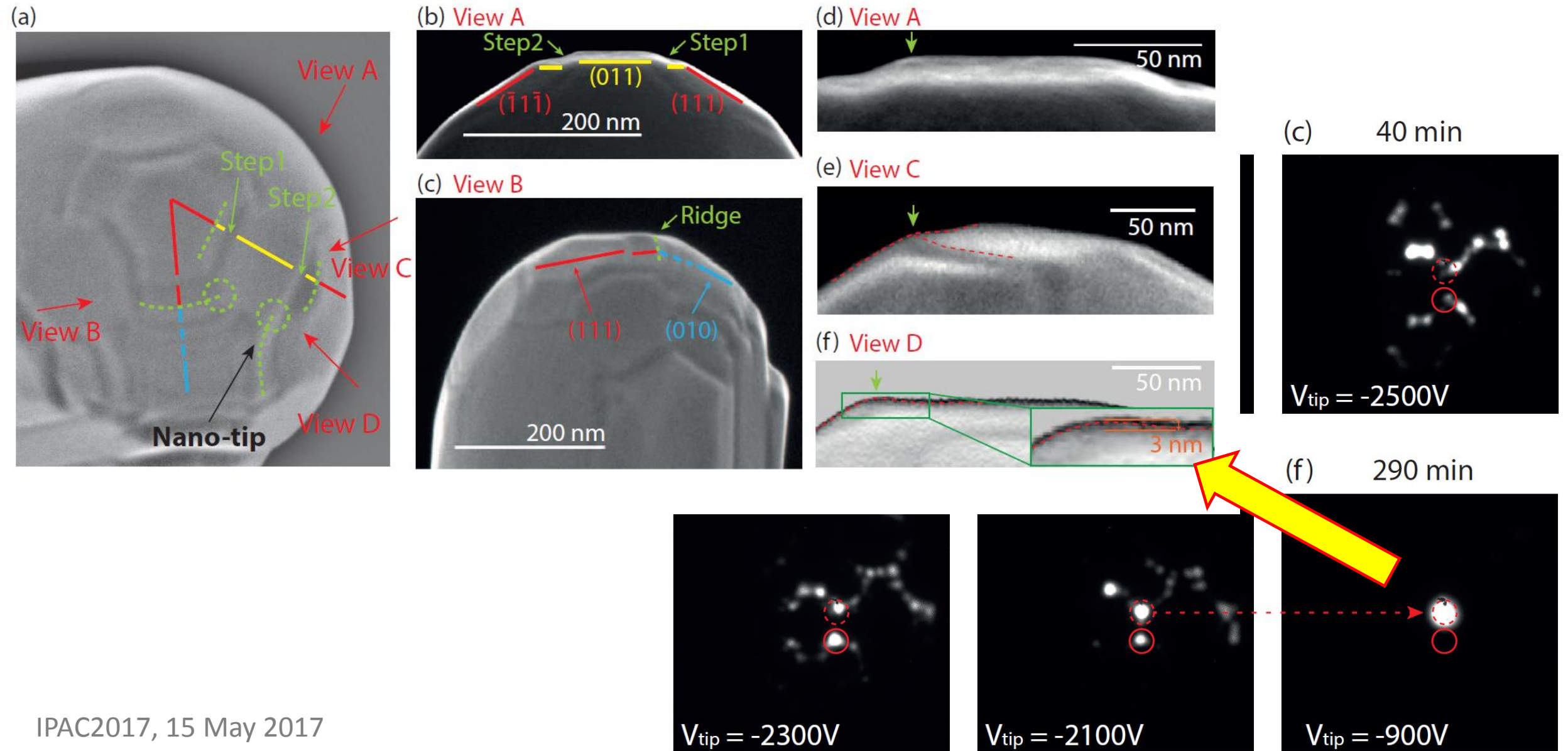
(e) 260 min



(f) 290 min

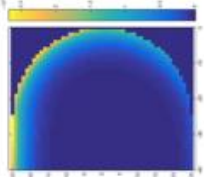
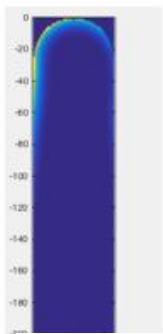


Identification of nm-sized emission site



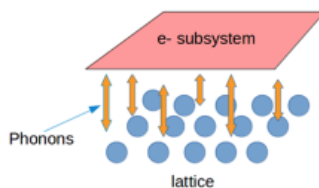
Electromagnetic field propagation

- Energy deposited on a tip by Joule heating
- Deposited energy was scaled to Gaussian laser pulse:
 - with peak of the pulse in the center of the tip
 - width of the Gaussian = half of the laser waist
- Deposited energy was used as an input for the Two Temperature model



Two temperature model

- Two separate subsystems: electrons and lattice.
- Each subsystem is in thermal equilibrium.
- Subsystems exchange energy through electron-phonon interaction.



$$C_e \frac{\partial T_e}{\partial t} = \nabla \cdot (k_e \nabla T_e) - G(T_e - T_l) + A(\vec{r})$$

T_e - electronic temperature, T_l - lattice temperature

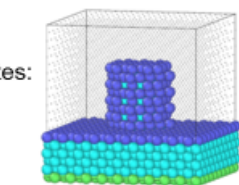
Kinetic Monte Carlo model under electric field

- Rigid lattice is assumed E
- Thermally activated jumps to vacant 1nn sites:

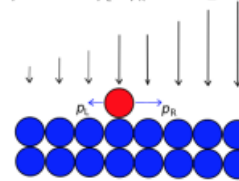
$$\Gamma = \nu e^{-\frac{E_{m'}}{k_b T}}$$

where ν is the attempt frequency, k_b - Boltzmann's constant, T - the temperature, and $E_{m'}$ - the migration barrier that an atom needs to overcome in order to make a jump.

- Adatoms on a surface become dipoles under electric field
- Migration barriers are affected by electric field
- Diffusion will be biased towards higher fields
- Bias is defined by the adatom's polarisability



probabilities $p_L < p_R$



More details in V. Jansson's talk

Kinetic Monte Carlo Results

